# Thermoelectric Scanning Gate Interferometry on a Quantum Point Contact

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We introduce a new scanning probe technique derived from scanning gate microscopy (SGM) in order to investigate thermoelectric transport in two-dimensional semiconductor devices. The thermoelectric scanning gate microscopy (TSGM) consists in measuring the thermoelectric voltage induced by a temperature difference across a device, while scanning a polarized tip that locally changes the potential landscape. We apply this technique to perform interferometry of the thermoelectric transport in a quantum point contact (QPC). We observe an interference pattern both in SGM and TSGM images, and evidence large differences between the two signals in the low density regime of the QPC. In particular, a large phase jump appears in the interference fringes recorded by TSGM, which is not visible in SGM. We discuss this difference of sensitivity using a microscopic model of the experiment, based on the contribution from a resonant level inside or close to the QPC. This work demonstrates that combining scanning gate microscopy with thermoelectric measurements offers new information as compared to SGM, and provides a direct access to the derivative of the device transmission with respect to energy, both in amplitude and in phase.

## I. INTRODUCTION

In the context of emerging quantum technology and in view of the increasing care for energy harvesting, thermoelectric transport in nanomaterials and nanodevices has recently regained interest [\[1,](#page-6-0) [2\]](#page-6-1). This has led to novel quantum thermal devices such as caloritronics interferometers [\[3\]](#page-6-2). The ability to accurately measure heat transport in two-dimensional systems [\[4\]](#page-6-3) and atomic junctions [\[5\]](#page-6-4) improved our global understanding of quantum thermodynamics, and shed light on mechanisms at play in complex many-body problems [\[6–](#page-6-5)[8\]](#page-6-6). Investigating these thermal effects at the local scale is challenging, but lots of efforts are also made in this direction. As an example, heat dissipation was recently mapped inside a graphene nanodevice with unprecedented thermal and spatial resolutions [\[9\]](#page-6-7), unveiling new mechanisms responsible for current-to-heat conversion in graphene [\[10\]](#page-6-8).

Here we introduce a new scanning probe technique based on the Seebeck effect, in order to investigate the temperature-to-voltage conversion at the local scale within a quantum device [\[11,](#page-6-9) [12\]](#page-6-10). This probe, which we call Thermoelectric Scanning Gate Microscopy (TSGM), is applied to study the puzzling low-density regime of quantum point contacts (QPC) [\[13,](#page-6-11) [14\]](#page-6-12) . Our experiments unveils unexpected features in the thermopower that are not visible in conductance measurements. We explain these deviations by the enhanced sensitivity of the thermopower to phenomena occurring at low transmission. This observation may help to clarify the nature of the conductance and thermoelectric anomalies in QPCs.

QPCs are quasi-one-dimensional ballistic channels in high-mobility two-dimensional electron gases (2DEG). Their conductance curves versus split-gate voltage show quantized plateaus at integer multiples of  $2e^2/h$  as a consequence of ballistic transport [\[15\]](#page-6-13). They also show anomalous features that are believed to result from electron-electron (e-e) interactions. The conductance exhibits a shoulder-like feature known as the 0.7 anomaly [\[16\]](#page-6-14), which disappears as the temperature is lowered. Additionally, the differential conductance exhibits a zerobias peak at very low temperature, known as the zerobias anomaly (ZBA) [\[17\]](#page-6-15). Many different models have been proposed to explain these anomalies, but after decades of investigations, their exact microscopic origin still remains a matter of intense debate [\[16](#page-6-14)[–23\]](#page-7-0).

The thermoelectric properties of QPCs have also been studied [\[24\]](#page-7-1) and were shown to be excellent probes of quantum confinement effects. The Seebeck coefficient  $S = \left(\frac{\partial V}{\partial T}\right)_{I=0}$ , relates variations of voltage V to temperature  $T$  in the absence of current  $I$ . It has been shown to oscillate with the number of transmitted modes in the QPC [\[25\]](#page-7-2). The thermal conductance and Peltier coefficients show similar behavior [\[26\]](#page-7-3).

In a single-electron picture,  $S$  is linked to the conduc-



<span id="page-1-1"></span>FIG. 1. (a) Scheme of the TSGM experiment: one side of the device is brought to higher temperature and the thermovoltage is recorded while scanning the polarized tip. (b) Seebeck effect across a barrier (black region): red and blue bars illustrate the energy distribution of charge carriers on the hot and cold sides. If transmission is energy-dependent, fluxes of hot and cold carriers are imbalanced. At equilibrium, a charge accumulation on the cold side restores a total balance of fluxes: this builds the thermovoltage  $V_{th}$ . (c) Differential conductance G, measured using a 4-probes technique at 25 mK (blue) and thermovoltage measured using a heating current of 180 nA (red) versus gate voltage  $V_g$ . (d) Theoretical transmission (blue) and Seebeck coefficient (red) calculated from the saddle-point model [\[15\]](#page-6-13) versus energy, for  $\omega_x/\omega_y = 0.6$ .

tance G through Mott's relation [\[27\]](#page-7-4):

<span id="page-1-0"></span>
$$
S^{M}(\mu, T) = -\frac{\pi^{2} k_{B}^{2} T}{3e} \frac{1}{G(\mu, T)} \frac{\partial G(\mu, T)}{\partial \mu}, \qquad (1)
$$

where  $\mu$  is the chemical potential. However, the thermopower is predicted to be sensitive to e-e interactions, and often reveals different information compared to the conductance. For example, in the case of Coulomb blockade, thermopower measurements probe the excitation spectrum rather than the addition spectrum [\[28,](#page-7-5) [29\]](#page-7-6). Since the thermopower is sensitive to the slope of the local density of states (DOS), it may be a useful probe of correlated behavior [\[30,](#page-7-7) [31\]](#page-7-8), which makes it very relevant in the case of QPC anomalies. Large deviations from Eq.[\(1\)](#page-1-0) have indeed been reported in QPCs below the first conductance plateau [\[32\]](#page-7-9), and were attributed to the important role of e-e interactions in this regime.

In this paper, we present an additional perspective on the low-transmission regime of QPCs, through interferometric Seebeck measurements performed with our novel TSGM technique. This new microscopy mode is a variant of the scanning gate microscopy (SGM) where the negatively polarized tip of a low-temperature scanning probe microscope is scanned above the surface, while recording tip-induced changes in the device's conductance [\[33,](#page-7-10) [34\]](#page-7-11). In TSGM, the device's Seebeck coefficient S is recorded instead of its electrical conductance [\[35\]](#page-7-12). One of the two electron reservoirs is heated using a low frequency AC current and the thermovoltage  $V_{th}$  across the device is measured as a function of the tip position (Fig[.1a](#page-1-1)). The Seebeck coefficient is obtained as  $S = V_{th}/\Delta T$  where  $\Delta T$ is the temperature difference (Fig[.1b](#page-1-1)).

In SGM images of QPCs, when the tip voltage is chosen such as to locally deplete the 2DEG, it generates fringes spaced by half of the Fermi wavelength due to Fabry-P<sub>e</sub> erot interference between the depleted region below the tip and the constriction defined by the split gate [\[33,](#page-7-10) [36,](#page-7-13) [37\]](#page-7-14). These fringes are observed both in SGM and TSGM images, but with significant differences near the QPC pinch-off. These differences cannot be explained in the framework of Mott's relation  $(Eq.(1))$  $(Eq.(1))$  $(Eq.(1))$ , indicating the crucial role played by the electron interactions in this regime. Understanding this many-body physics has been a research topic for decades, and is beyond the scope of the present paper.

Instead, we analyze in more details the thermoelectric scanning gate interferometry technique in a singleparticle framework. We propose a microscopic model incorporating the contribution of a resonant energy level located close to the QPC, to simulate the SGM and TSGM signals. We show explicitly that the different connection of G and S to the slope of the density of states at the Fermi energy results in an enhanced sensitivity of S to localized states with weak transmission. This property makes the TSGM technique particularly relevant for the investigation of the low-density regime of QPCs where spontaneous localized states have been predicted [\[38\]](#page-7-15) and observed [\[17,](#page-6-15) [39\]](#page-7-16).

# II. DESCRIPTION OF THERMOPOWER MEASUREMENTS

The device chosen to illustrate this new experimental technique is a QPC, defined in a GaAs/AlGaAs heterostructure by a 270-nm-long and 300-nm-wide gap of a Ti/Au split gate. The 2DEG located 105 nm below the surface has  $2.5 \times 10^{15}$  m<sup>-2</sup> electron density and  $1.0 \times 10^{6}$  $\text{cm}^2\text{/V.s}$  electronic mobility at low temperature. The device is thermally anchored to the mixing chamber of a dilution fridge in front of a cryogenic scanning probe microscope [\[40\]](#page-7-17) and cooled down to a base temperature of 25 mK. The four-probe differential conductance is measured by a lock-in technique using a 10  $\mu$ V excitation, at 77 Hz. A series resistance of 200  $\Omega$  is subtracted from all data in order to have the first conductance plateau at  $2e^2/h$ . The lever-arm parameter of the split gate  $\alpha = 54$ meV/V is deduced from the non-linear spectroscopy of the QPC subbands separated by  $\Delta E = 3.5$  meV (see Fig. S1 in the supplemental materials [\[41\]](#page-7-18)).

To measure the Seebeck coefficient of the QPC, we use the electron-heating technique depicted in Fig. [1a](#page-1-1). We inject an AC current at 7.17 Hz between two contacts on the same side of the QPC, and record the voltage across the QPC using a lock-in detection at twice the heating frequency (14.34 Hz), in order to be sensitive



<span id="page-2-0"></span>FIG. 2. (a) Black curve:  $-S^{M}/T$  calculated using Mott's law from the  $G(V_g)$  curve at 25 mK (dashed line). Colored curves:  $-S/T = (V_{th}/\Delta T)/T_{\text{average}}$  scaled to the black curve at the third peak summit using  $\Delta T$  as the only fitting parameter. Heating currents range from 50 to 240 nA (blue to red). (b) Temperature difference  $\Delta T$  as a function of the heating current. Inset: Electron microscope image of the device. The scale bar is 5  $\mu$ m. (c)  $S/T - S^M/T$  for temperature differences from 160 to 570 mK (blue to red) as a function of  $V<sub>g</sub>$ . Same data as in (a).

to the dissipated power only and avoid any contribution related to the electrical conductance [\[26\]](#page-7-3). The thermovoltage recorded versus gate voltage  $V_g$  is shown in Fig. [1c](#page-1-1) together with the measured conductance curve. As expected theoretically[\[24\]](#page-7-1), the thermovoltage oscillates between minimum values when the QPC is on a plateau and maximum values for transitions between plateaus. For comparison, the transmission and Seebeck coefficients expected from a non-interacting saddle-point model [\[15\]](#page-6-13) are plotted in Fig. [1d](#page-1-1).

A crucial issue in thermopower measurements is to relate the applied heating current to an actual temperature difference  $\Delta T$ . To evaluate this quantity, we use two independent methods. First, we use Mott's law for high densities, assuming that it is valid when more than 2 modes are transmitted through the QPC, and compare quantitatively the measured value  $S$  with that predicted by Mott's law  $S^M$ . This comparison indicates the existence of a heating-current-dependent but gate-voltage-independent background in the measured signal (see Fig. S3 in the supplemental materials [\[41\]](#page-7-18)). With this background contribution removed, the measured Seebeck coefficient should be given by Mott's relation applied to the measured conductance (black curve Fig. [2a](#page-2-0)). This is well verified for the third to fifth transitions, the only fitting parameter being the temperature difference.

Fig. [2b](#page-2-0) shows the temperature differences deduced from these assumptions, ranging from 100 to 800 mK for heating currents from 15 to 400 nA. Second, we compare these extracted values with estimates obtained from the temperature and current dependence of the Shubnikovde-Haas oscillations in our sample, and find a good agreement (see Fig. S4 in the supplemental materials [\[41\]](#page-7-18)). Note that the temperature difference is always larger than the average temperature, such that the system is far from the linear regime. Nevertheless, it has been shown that Mott's law holds even in this highly nonlinear regime, provided that  $\Delta T$  is smaller than the subbands spacing and smearing [\[42\]](#page-7-19).

Interestingly, the electronic temperature in the middle of the heated reservoir evolves sub-linearly with the heating current  $I_h$ , whereas one could naively expect a  $I_h^2$ dependence related to the dissipated Joule power. This can be explained by the non-linear temperature dependence of heat losses in 2DEGs, mostly due to phonon emission [\[43\]](#page-7-20) and electron out-diffusion in the ohmic contacts [\[4,](#page-6-3) [7\]](#page-6-16). These competing losses yield a non-uniform temperature profile and a sub-linear dependence on  $I_h$  of the local temperature far away from the ohmic contacts [\[44\]](#page-7-21).

In Fig[.2a](#page-2-0), the correspondence between  $S$  and  $S<sup>M</sup>$  does not hold when less than three QPC modes are transmitted, with three distinct features highlighted by the plot of their difference (see Fig. [2c](#page-2-0)): (i) in the transition from pinch-off to the first plateau ( $V_g \sim 0.74$  to -0.71 V), the difference is very large (positive) and increases with lowering temperature, (ii) on the first plateau ( $V_q \sim -0.71$ to -0.68 V), the difference is of opposite sign (negative) and forms a peak at the lowest temperatures, (iii) in the transition from the first to the second plateau ( $V_g \sim$  -0.68 to -0.64 V), a significant difference (positive) arises as  $\Delta T$  is lowered below 500 mK.

Differences between  $S$  and  $S^M$  in the low-density regime of QPCs have already been reported in Ref. [\[32\]](#page-7-9). In that work, a local minimum was observed in the thermopower at the position of the  $0.7 \times 2e^2/h$  anomalous conductance plateau at 2 K, as expected from Eq.[\(1\)](#page-1-0). However this minimum was shown to disappear into a shoulder at the lowest temperature of 300 mK, whereas the 0.7 plateau was still present (deviation from Eq.[\(1\)](#page-1-0)).

Here, the thermopower is also in contradiction with Mott's law but in a different way. The base temperature is much lower (25 mK) and the conductance curve does not show any 0.7 plateau (an absence related to the emergence of a zero-bias peak in the differential conductance [\[17\]](#page-6-15)). The thermopower however shows a peak at the lowest temperatures and a minimum around  $V_g = -0.705$  V that disappears for  $\Delta T$  above 500 mK (Fig[.2a](#page-2-0)).



<span id="page-3-0"></span>FIG. 3. (a) SGM image recorded when the QPC is open on the first plateau  $(V_q = -0.66 \text{ V})$ : conductance G as a function of tip coordinates. The QPC center is located at (-150 ; 0) nm on the left side of the image. (b) TSGM image of the thermopower in the same conditions, but recorded in a second pass while heating the reservoir on the opposite side of the scanning area. (c) Conductance and (d) thermovoltage as a function of gate voltage and tip position along the red line drawn in (a) and (b), recorded in the exact same conditions, but in separate tip scans. (e,f) Derivative of (a) and (b) with respect to tip position.

# III. THERMOELECTRIC SCANNING GATE MICROSCOPY

We now report on the TSGM experiment, i.e. the investigation of thermoelectric transport in presence of the scanning gate. The tip is scanned 50 nm above the sample surface with an applied voltage of -6V, which locally depletes the 2DEG. Fig. [3](#page-3-0) shows the SGM and TSGM images obtained by recording successively the conductance and the thermoelectric voltage in two different tip scans. The conductance signal is recorded using an AC excitation of 10  $\mu$ V, and the thermovoltage using a heating current of 150 nA, corresponding to a temperature difference of 450 mK. Both images look very similar, presenting interference fringes due to the Fabry-Pérot cavity formed by the QPC and the tip-depleted region. The TSGM image provides to our knowledge the first observation in real space of a thermally-driven electron interferometer.

Despite their apparent similarities, these images carry distinct information and one cannot be deduced from the other. Indeed, even in the range where Mott's rela-tion [\(1\)](#page-1-0) is valid, deducing the TSGM image  $S(x_{tip}, y_{tip})$ from the SGM  $G(x_{tip}, y_{tip})$  would require a knowledge of how the transmission evolves with the chemical potential  $(\partial G/\partial \mu)$ . Most of the time, this quantity is not available in GaAs 2DEG, since it requires a backgate to vary the global electron density[\[45,](#page-7-22) [46\]](#page-7-23), which is a real challenge in high-mobility GaAs heterostructures.

In Fig[.2a](#page-2-0), the chemical potential of the QPC itself was identified as being proportional to  $V_g$ , which is a reasonable approximation when considering only the QPC transmission. In TSGM images, the distant influence of the tip does not allow such an identification, since the studied system now consists of the QPC coherently coupled to the tip-induced Fabry-Pérot cavity. As a consequence, the chemical potential of the system is not linearly linked to  $V_g$ , and TSGM images provide a different information than what is obtained from SGM.

To illustrate these differences, we study the evolution of the interference fringes as a function of the QPC opening. The conductance  $G$  and the thermo-voltage  $V_{th}$  are recorded separately while scanning the tip along the line shown in Fig. [3\(](#page-3-0)a,b), using an excitation of 15  $\mu$ V and a temperature difference of 450 mK for  $G$  and  $S$  measurements, respectively. The evolution of the interference fringes with  $V_g$  is shown in Fig[.3\(](#page-3-0)c,d), for the conductance and thermovoltage signals. The fringes are similar in both signals but are superimposed on two very different background signals : a series of conductance plateaus for  $G$ , and a series of peaks for  $V_{th}$  (see Fig[.2\)](#page-2-0), including a very strong peak at the QPC pinch-off. To highlight the fringes' evolution with  $V_g$ , we plot the first derivative of both signals with respect to the tip position along the red line,  $d_{tip}$ , and plot the results in Fig[.3\(](#page-3-0)e,f). In these maps, we observe a complex evolution of the interference fringes, which looks globally similar in  $G$  and  $S$ , though few differences can be detected.

In the following, we focus on the low conductance regime, below  $\sim 0.5 \times 2e^2/h$ , where S and S<sup>M</sup> differ by a large amount (Fig. [2c](#page-2-0)). In this regime, the SGM and TSGM interferometric signals evolve differently with gate voltage. The conductance oscillations follow a monotonic behavior (Fig[.4a](#page-4-0),c), i.e. their phase evolves monotonically with gate voltage, whereas the thermopower oscillations exhibit an abrupt phase shift at a conductance of about  $0.25 \times 2e^2/h$  (Fig. [4b](#page-4-0),d), which can also be surmised in Fig[.3d](#page-3-0),f. A Fourier analysis (Fig. [4e](#page-4-0)) indicates that the phase shift observed in the thermopower is almost  $\pi$ . Similar phase shifts have been observed in the conductance signal in many different devices during our previous experiments [\[47\]](#page-7-24). However they were observed at higher transmission, close to the first conductance plateau. Here the phase shift is observed in the thermopower at very low transmission, where no phase shift is present in the conductance.



<span id="page-4-0"></span>FIG. 4. (a) Conductance and (b) thermovoltage as a function of gate voltage and tip position along the red line drawn in Fig. [3,](#page-3-0) where  $d_{tip}$  here denotes tip position between 250 and 650 nm in Fig[.3c](#page-3-0)-f. (c,d) Derivative of (a) and (b) with respect to tip position. (e) Phase of the interference fringes as a function of gate voltage extracted from the conductance (purple) and thermovoltage (green), following the pinch-off lines shown in (c) and (d) to account for cross-talk effect. (f) Line profiles of  $G, -S^M/T$  and  $-S/T$  extracted along the red and blue lines in (a) and (b).

#### IV. DISCUSSION

Phase shifts in the conductance were previously observed in Aharonov-Bohm interferometers containing a quantum dot in one arm, where the interference pattern experiences a phase shift by  $\pi$  whenever one charge is added to the quantum dot [\[48\]](#page-7-25), and by  $\pi/2$  in the Kondo regime [\[49\]](#page-7-26).

Similarly, the phase shift observed in our SGM-based interferometry experiment indicates the presence of a resonant level in the cavity formed by the QPC and the tip. Such a resonant level could be located in the QPC itself, as observed in Ref. [\[22\]](#page-7-27), or in the 2DEG region between the QPC and the tip, as a result of potential fluctuations induced by remote ionized dopants. In the latter case, the phase shift of the interference pattern would barely depend on the QPC gate voltage. Experimentally however, the phase shift evolves with gate voltage following exactly the QPC pinch-off line (Fig[.4d](#page-4-0)), suggesting that this resonant state is in the close vicinity of the QPC.

Alhough this localized state could result from disorder in the potential of the QPC channel, it could also correspond to a spontaneously localized charge. Indeed, several evidences for the existence of bound states in QPCs near pinch-off have been reported [\[39,](#page-7-16) [52](#page-7-28)[–56\]](#page-8-0). Such bounds states have been predicted to spontaneously form

in QPCs by several numerical studies [\[51,](#page-7-29) [57–](#page-8-1)[60\]](#page-8-2), as a consequence of e-e interactions. When the potential barrier of the QPC is above the Fermi level, there are two regions of low density, one on each side of the barrier, where charges could spontaneously localize. Numerical simulations of this peculiar situation encountered near pinch off supports the presence of bound states [\[61,](#page-8-3) [62\]](#page-8-4) detected in coupled QPCs experiments [\[54,](#page-7-30) [63\]](#page-8-5). This scenario has also been proposed in Ref.[\[64\]](#page-8-6) to explain the presence of QPC conductance anomalies down to very low conductance. This is also consistent for example with the results of local spin density functional theory presented in Ref.[\[18\]](#page-6-17), where two charges are shown to be localized on both sides of the main barrier at low density. Finally, classical electrostatic simulations also confirm that at low QPC transmission, two one-dimensional regions form on both sides of the channel, where the density is low enough to induce Wigner crystallization [\[65\]](#page-8-7) (see section VI in the supplemental materials [\[41\]](#page-7-18)).

It should be mentionned, however, that some experiments [\[67\]](#page-8-8) found no sign of such a localized state, and that some theoretical works proposed an alternative explanation for the related 0.7 and zero-bias anomalies [\[20,](#page-6-18) [66\]](#page-8-9), whithout invoking the presence of a localized charge. Note also that, in presence of interactions, Friedel oscillations between the QPC barrier and the SGM tip [\[50,](#page-7-31) [51\]](#page-7-29) could give rise to a phase shift of the interference pattern, but this effect is not expected to appear as abruptly versus gate voltage as it is observed here.

In conclusion, the phase shift observed here by TSGM at very-low transmission is probably related to the presence of a localized state on the side of the QPC, but distinguishing whereas this state is induced by e-e interaction or by disorder is beyond the scope of the present paper and would require additional investigation.

# V. EFFECT OF A LOCALIZED STATE IN TSGM INTERFEROMETRY

In this section, we use a simple microscopic model to analyze the effect of a localized state (irrespectively of its origin in this specific sample), on the SGM and TSGM interferometric signals. We model the gate-controlled potential in the QPC by a barrier with transmission rate  $\Gamma_L$  and we assume the presence of a localized state on the right side of the barrier, at an energy  $\epsilon_0$ , separated from the right reservoir by a barrier with transmission rate  $\Gamma_R$  (Fig[.5a](#page-5-0)). We also model the tip as a distant scatterer of transmission amplitude  $T_{tip} = 0.99$ , whose distance from the resonant level  $D_{tip}$  can be varied. The expression of the energy-dependent transmission  $T(E)$  through the whole system can then be calculated exactly as presented in Ref.[\[22\]](#page-7-27). In the Landauer framework, G and S



<span id="page-5-0"></span>FIG. 5. (a) Up: typical energetic potential which could lead to the proposed scenario: a localized state is located on the tip side of the main QPC barrier. Down: Scheme of the 1D model including, from left to right, the QPC barrier  $(\Gamma_L)$ , the localized state ( $\epsilon_0$  and  $\Gamma_R$ ), and the tip-induced cavity  $(D_{tip}$  and  $T_{tip}$ ). (b) Conductance of the resonant level as a function of its energy relative to  $\mu$  for fixed  $\Gamma_R = 0.2$  and  $\Gamma_L$  $= 0.2$  (blue) to 0.01 (red).(c) Seebeck coefficient in the same configuration. (d) Conductance evolution with  $\Gamma_L$  assuming that the resonant level, perfectly coupled to the right lead  $(\Gamma_R = 1)$ , crosses  $\mu$  at  $\Gamma_L = 0.1$  and then stays just below the Fermi level while the QPC opens. (e) Seebeck coefficient in the exact same scenario.  $(f,g)$ : Evolution of the Fabry-Pérot interference in this scenario: conductance (f) and Seebeck coefficient (g) as a function of tip distance and  $\Gamma_L$ . (h,i): Derivative of G and S with respect to  $D_{tip}$ .

respectively express as [\[68\]](#page-8-10):

$$
G = \frac{2e^2}{h}L_0\tag{2}
$$

$$
S = -\frac{1}{|e|T} \frac{L_1}{L_0} \tag{3}
$$

where

$$
L_m = \int_{-\infty}^{+\infty} (E - \mu)^m \left(\frac{\partial f}{\partial E}\right) T(E) \,dE,\tag{4}
$$

and  $f(E)$  is the Fermi distribution.

We first show that the behaviors with respect to the tunneling rates of asymmetric barriers are very different for G and S (Fig[.5b](#page-5-0)-c). For a fixed tunneling rate  $\Gamma_R =$ 0.2 (in units of the hopping term  $t$ ), the effect of a decrease in  $\Gamma_L$  is opposite for G and S: it tends to decrease G, which is dominated by the lowest tunneling rate, but to increase S on both sides of the resonance since it is sensitive to the resonance sharpness, and thus inversely proportional to  $\Gamma_{tot} = \Gamma_L + \Gamma_R$ .

In the following, we assume that the resonant state is very well coupled to the right lead  $(\Gamma_R \text{ fixed at } 1)$  and that it evolves with  $\Gamma_L$  as shown in the inset of Fig[.5e](#page-5-0). As the QPC is progressively opened from the pinch-off (increasing of  $\Gamma_L$ ), the energy of the resonant state  $\epsilon_0$  drops until it reaches the Fermi level at  $\Gamma_L = 0.1$  (dashed line in Fig[.5d](#page-5-0)). Opening the QPC further does not change  $\epsilon_0$ , but the level stays pinned close to  $\mu$ , up to the point where  $\Gamma_L = \Gamma_R$  and the transmission reaches unity. In this scenario, the conductance behaves as normally expected for a QPC (Fig[.5d](#page-5-0)): the resonance is almost invisible as it appears close to the pinch-off. It also gives no discernible signature in the interference fringes, since it occurs at very low transmission (Fig[.5f](#page-5-0) and [5h](#page-5-0)). The high sensitivity of S results from the strong variation of the transmission with energy when the resonance approaches the Fermi level.

The phase shift induced by the drop of  $\epsilon_0$  below  $\mu$ is highly visible in S, and is due to the Breit-Wigner like resonance of the localized state, that induces a total  $\pi$  phase shift when the level crosses the Fermi energy. Since the Fabry-Pérot cavity probes twice the resonant level phase shift in case of a strong coupling on the cav-ity side[\[22\]](#page-7-27), the total phase shift should be  $2\pi$ . However assuming that the  $\epsilon_0$  level falls just below  $\mu$  but remains at a constant energy value, the phase shift remains half the value of  $2\pi$ , which corresponds to the experimentally observed  $\pi$  value. This model therefore provides a plausible scenario to understand our TSGM interferometry results

## VI. CONCLUSION

In conclusion, we introduced a new scanning probe technique to image thermoelectric transport through a QPC. By scanning the polarized tip in front of the QPC, we imaged for the first time interference of electrons driven by a temperature difference, in analogy with the well-established SGM experiments where the electron flow is driven by a voltage difference. In addition, we showed that in the very-low-conductance regime, the thermopower interference fringes experience an abrupt phase shift, invisible in the conductance signal. We propose a simple 1D model to show that this phase shift and its characteristics can be explained by the contribution of a localized state inside or close to the QPC, and that stays pinned to the Fermi energy of the leads as the first QPC mode opens. The fact that this localized state signature is hidden in conductance measurements but highly visible in the Seebeck coefficient is explained by its sharp-

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ness and occurrence at low transmission. This work illustrates that the combination of scanning gate microscopy and thermoelectric measurements can unveil elusive phenomena that escape transport measurements. Though we cannot draw definitive conclusions on the mechanism leading to this localization, we provide a new tool that may prove useful in future investigations of conductance and thermoelectric anomalies in QPCs.

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# Thermoelectric Scanning Gate Interferometry on a Quantum Point Contact - Supplemental materials -

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#### I. SUBBANDS ENERGY SPACING



FIG. S1: Lever-arm parameter of the split gate: (a) Electron microscope image of device, and scheme of the heating current. (b) Differential conductance G versus gate voltage  $V_g$ , measured in 4-probes at 25 mK. (c) Non-linear conductance traces  $G(V_{ds})$  for gate voltages spaced by 1.25 mV. (d) Derivative of G versus  $V_g$  as a function of  $V_{ds}$  and  $V_g$ , showing the energy spacing  $\Delta \overline{E}$  between the quasi-1D subbands, which are separated by  $\Delta V_g$  in gate voltage.

The lever-arm parameter  $\alpha$  of the split gate, relating the potential energy in the constriction to the voltage applied on the split gate, is deduced from the non-linear conductance traces shown in Fig. S1 (c) and (d). The energy spacing between the first and second subband is  $\Delta E_{1-2} = 3.5$  meV, and corresponds to a change in gate voltage  $\Delta V_g = 0.065$ V. The lever-arm parameter of the split gate is therefore taken as  $54\pm5$  meV/V.

#### II. ZERO-BIAS CONDUCTANCE ANOMALY



FIG. S2: Evolution of the zero-bias anomaly with temperature: Non-linear conductance traces  $G(V_{ds})$  for gate voltages spaced by 1.25 mV versus DC source-drain bias  $V_{ds}$ , at 25 mK, 250 mK, 500 mK and 1 K.

The zero-bias anomaly is visible below the first conductance plateau. At a base temperature of 25 mK its full-width at half maximum is  $\Delta V \sim 300 \mu\text{eV}$ . This corresponds to a Kondo temperature  $T_K = \frac{e\Delta V}{k_B} \sim 1.7 \text{ K}$ . The ZBA shades off for temperatures above 500 mK and has almost disappeared at 1 K.

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FIG. S3: Temperature-dependent background in the thermoelectric voltage: (a) Electron microscope image of the device. The scale bar is 5  $\mu$ m. (b) Raw data of the measured  $V_{th}$  versus  $V_g$ , for heating currents ranging from 15 nA (blue curve) to 240 nA (red curve). (c) Minimum thermovoltage between the first and second thermovoltage peaks at  $V_g = -0.62$ V, plotted as a function of the heating current. This value corresponds to the gate-voltage-independent background which is subtracted in Fig. 2a of the main paper before the evaluation of the temperature difference. (d) Seebeck coefficient of the background signal obtained by dividing the thermovoltage by the estimated temperature difference  $\Delta T$ , extracted using the Mott's law (Fig. 2b of the main paper)

In our experimental setup, the thermoelectric voltage is measured between two ohmic contacts and includes several contributions : (i) the thermovoltage across the QPC which is the interesting signal, (ii) a thermovoltage in the 2DEG due to a temperature gradient inside the heated reservoir, and (iii) a thermovoltage at the junction between the heated 2DEG reservoir and the ohmic contact. We assume here that the ohmic contacts are thermalized at the fridge temperature. The thermovoltage at the QPC is the gate-voltage-dependent signal, whereas the two others contributions form the gate-voltage-independent signal, called background (see Fig. S3a). longbibliography For each heating current, the background is defined as the thermovoltage value in the second minimum of the curve, at  $V_g = -0.62$  V. Since the temperature of both reservoirs is always kept lower than the subband energy spacing  $(\Delta E/k_B \sim 40 \text{ K})$ , we indeed have  $dG/dV_g = 0$  on the plateaus, and the thermovoltage at the QPC should drop to zero. The dependence of this background on the heating current is shown in Fig. S3b. Using the evaluated temperature differences as a function of the heating current (see main paper), we can estimate the thermopower corresponding to the observed background (Fig.S3c), and we find a value around 2.5  $\mu$ V/K which depends weakly on the heating current.

In the following, we discuss quantitatively the origin of this background signal. The thermopower of the 2DEG can be separated in two main contributions: the thermopower due to the phonons, usually called the phonon drag, and the diffusion thermopower, that can be expressed as:

$$
S^{d} = \frac{\pi^{2} k_{B}^{2} T}{3 e E_{F}} (p+1)
$$
\n(1)

where p represents the dependence of the electrons scattering rate with energy, that depends on the scattering mechanism but is close to unity [1]. In our case, this expression yields  $S^d = 0.1 \mu V/K$  at the lowest temperature, and rises up to  $S^d = 0.5 \mu V/K$  for the largest applied temperature differences. The 2DEG diffusion thermopower can therefore not account alone for this background. The contribution of phonons could be invoked, but it is likely that

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the phonon drag does not contribute to the thermopower in our case, due to the sub-Kelvin temperature, regarding other works[1–3]. The thermopower due to the ohmic contacts is not well characterized, and might be responsible for this background signal, together with a small contribution from the 2DEG as discussed above.



IV. TEMPERATURE ESTIMATED FROM SHUBNIKOV-DE-HAAS (SDH) OSCILLATIONS

FIG. S4: Temperature and AC current dependence of Shubnikov-de-Haas oscillations: (a) SdH oscillations for temperatures ranging from 25 mK to 1 K. The applied AC current is 50 nA and a series resistance of 2.4 kΩ is subtracted to account for filters and contacts resistance (2-probes measurements). (b) SdH oscillations for AC current ranging from 25 nA to 400 nA at the base temperature of 25 mK. (c) Amplitude of SdH oscillations as a function of mixing chamber temperature, and polynomial fit for each Landau level. (d) Amplitude of SdH oscillations as a function of applied AC current, and polynomial fit for each Landau level. (e) Combination of the two polynomial fits to obtain temperature as a function of AC current. The temperature of the hot reservoir extracted from the thermovoltage analysis using the Mott's law is plotted as squares for comparison.

To reproduce the same geometry as in the thermopower measurement, the SdH oscillations (Fig. S4a and S4b) are measured between the two contacts located on the same side of the QPC, and a split gate voltage lower than the depletion threshold is applied. We used  $V_q = -0.65$  V corresponding to one mode open in the QPC but we checked that the results do not change if the QPC is closed at  $V_g = -0.75$  V. Fig. S4e presents the estimation of the current-induced 2DEG temperature obtained from the analysis of the SdH oscillations amplitude versus temperature (Fig. S4c) and versus current (Fig. S4d). The estimated temperatures vary a bit with the filling factor, but remain in the same range. This estimation indicates a similar order of magnitude as the temperatures evaluated from the thermovoltage analysis using the Mott's law (squares). The similarities between the two methods disappear below 300 mK. This is not surprising as the temperature evolution of the SdH oscillations was measured with a large current of 50 nA to have a reliable signal, corresponding to a current-induced temperature of about 200 mK.

It shall also be noted that the temperature profile is expected to be non-uniform in the heated region [4]. Hence SdH oscillations may be affected by the overall temperature profile whereas the estimated temperature difference obtained from the QPC thermovoltage is sensitive to the local temperature in its close vicinity. This could account for the observed differences between the two methods.

The sub-linear dependence of the temperature difference on heating current (Fig. S4e here and Fig. 2b of the main paper) can be explained in the framework of heat dissipation in 2DEGs. When electrons are brought to an electronic

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temperature  $T_e$  higher than the phonon temperature  $T_{ph}$  they can lose energy via different mechanisms. The dominant ones at low temperatures are the phonon emission [5], which evolves as  $T_e^5$ , and the electron out-diffusion in the ohmic contacts, which evolves as  $T_e^2$  as accurately verified down to the quantum limit of a single electronic channel [6, 7]. These competing losses yield a non-uniform temperature profile and a sub-linear dependence of the local temperature on the heating current [4].

#### V. CORRELATION BETWEEN PHASE SHIFT AND CHANGE IN THE NUMBER OF LOCALIZED CHARGES

In Fig.S5 we explain how the phase shifts of the interference fringes are connected with a change by one in the number of charges localized in the QPC. The QPC presented here has the same geometry as the one in the present paper but is a different sample. Its transport charlongbibliographyacteristic are detailed in ref.[8]. We describe here our understanding of this phenomenon, which is a generic feature and is not sample specific, and has also been reproduced since by an other group. (Beat Braem, ETH Zürich, *private communication*).

Below the first conductance plateau, the 1D electronic density in the QPC is so low that a definite number of charges spontaneously localize due to Coulomb repulsion, in a mechanism similar to Wigner crystallization. This number of charges can be changed by moving the tip in front of the QPC, which affects the QPC potential and the size of the crystal. This effect is visible as concentric rings in the SGM image recorded below the first plateau Fig.S5a. These rings correspond to alternating single-peak or split-peak zero-bias anomalies (Fig.S5d) matching respectively with an odd or even number of localized charges. Dashed lines on Fig.S5a indicate tip positions leading to a change in the number of localized charges.

The number of localized charges can also change as a function of QPC opening (with  $V_g$ , not shown here). The modulations visible in the conductance traces at zero bias are really generic and correspond to a ZBA that spontaneously splits as the QPC opens or its shape is varied [9–11]. The tip position and gate voltage affect differently the number of localized charges but *loci* of changes in this number can be followed in colormaps of conductance versus  $V_g$  and  $d_{tip},$  as indicated by dashed lines in Fig.S5g and S5h.  $\,$ 

Along the scan line 1, the changes in the number of charges is the only phenomenon affecting transport, hence they are easy to follow. Along line 2 however, this is less trivial. The tip that depletes the 2DEG underneath is scanned above preferential electron trajectories (branching). As a consequence, Fabry-Pérot interference fringes as a function of tip position are visible. Nevertheless, changes in the number of charges can still be visualized by differentiating the signal with respect to  $V_g$ , and interference can be highlighted by differentiating the signal with respect to  $d_{tip}$ . By placing dashed lines corresponding to a change in the number of localized charges on Fig.S5j and S5k, one can see that a change in this number is correlated with an abrupt phase shift of  $\pi$  in the interference fringes. The most visible case is highlighted in Fig.S5l. This case is clearer because the tip is far from the QPC, hence changes in the number of charges are spaced by more than 100 nm in the tip position. When the tip is closer to the QPC, the phase shift is really hard to distinguish because these changes are separated by less than one hundred nanometer, which corresponds to only one or two Fabry-Pérot oscillations. It is therefore very difficult to see a phase shift by  $\pi$ occurring only for one or two interference fringes, which leads to blurred and very large oscillations.

For the sample whose data are discussed in the main text, we were forced to scan the tip close to the QPC due to a dust particle on the sample surface, located at about  $1 \mu m$  away from the QPC. In this region, the number of localized charges changes rapidly with tip position and produce several phase shifts in the interference pattern. In Fig. 4c of the main paper, there are probably two changes in the number of localized charges that produce the two distortions visible in the interference pattern.

The abrupt phase shift observed in TSGM as a function of gate voltage at the very pinch-off (Fig. 4d of the main paper) looks really similar to those observed in SGM in previous samples, but it differs in two main aspects:

- It evolves parallel to the QPC pinch-off line controlled by the cross-talk between the split gate and the scanning gate, whereas other observed phase shifts follow a different evolution (the green dashed lines in Fig.S5 are not parallel the line corresponding to the cross-talk)

- It is visible at very low transmission, lower than for any phase shift observed by the authors in their previous works. These two differences suggest that, in the regime of very low transmission, the localized charges are not sensitive to the tip potential, whose only effect is to curve the pinch-off line.

A more puzzling property of this phase shift is that it is only visible in the thermovoltage and not in the conductance. We currently have no explanation for this anomalous behavior. Even if we know that the Mott's law does not hold in this regime of strong electron interactions, one would not expect such an all-or-nothing difference (phase shift or no phase shift) between the thermopower and the conductance. This really surprising difference indicates indeed that the thermopower and the conductance are significantly different spectroscopic tools, and may be sensitive to different aspects of an interacting mesoscopic system.



FIG. S5: Correspondence between phase shifts in the interference fringes and changes in the number of localized charges, in a similar sample (see Ref. [8]): (a,b) SGM maps of the conductance G for gate voltages: (a) below the first plateau at  $V_g = -1$  V and (b) on the first plateau at  $V_g = -0.95$  V. (c) Scheme of spontaneously localized charges with a net spin S=1/2 ground state (upper panel) and a net spin S=0 ground state (lower panel). (d) Differential conductance G versus source-drain bias at a fixed gate voltage  $V_g = -1$  V for different tip positions from 0 to 450 nm along the line 1 indicated in (a,b). Successive curves are shifted upwards by  $0.0075 \times 2e^2/h$ . (e) Color plot of the same data as in (d) after subtraction of a smooth background to suppress the main gating effect of the tip. Peak positions are indicated by dots. The successive ZBA splittings give a checkerboard pattern. (f,i) Traces  $G(V_g)$  for several tip positions along the lines 1 and 2 indicated in (a,b). The curves are shifted in  $V_g$  for clarity. (g,j) Color-plot of the same data, differentiated with respect to gate voltage  $(\partial G/\partial V_g)$ . (h,k) Color-plot of the same data, differentiated with respect to tip position along these lines  $(\partial G/\partial d_{tip})$ . The different parities of the number of charges localized in the QPC are indicated by blue (even) and red (odd) dots. Green dashed lines represent changes by one electron charge. (l) Zoom of (k) showing a region with a single change in the charge number, highlighting a phase shift of the interference.

#### VI. CLASSICAL ELECTROSTATIC SIMULATIONS



FIG. S6: Self-consistent electrostatic simulations for different gate voltages: (a)  $V_{gate}$  = -0.8 V. (b)  $V_{gate}$  = -0.8 V. (c)  $V_{gate}$ -0.78 V. The Fermi energy is  $E_F = 8$  meV. Red lines: gates geometry. Colorscale: 2D-density in the 2DEG plane. The spacing between the dashed lines indicate the electron spacing, and each black or grey disk contains one electron charge. The spacing between the two pink lines give the Fermi wavelength, and the 1D region corresponds to the region where these lines intersect with the zero-density black lines. The blue lines in (d-f) represent the 1D electron density integrated along the y-direction. In the 1D region (dashed lines), the 1D density is below the critical value for 1D Wigner crystallization.

We perform self-consistent classical electrostatic simulations to estimate how a localized state could form in our geometry, near pinch-off. The mesh grid is computed using Gmsh (http://gmsh.info) and the electrostatic problem is solved self-consistently using a modified version of MaxFEM (http://www.usc.es/en/proxectos/maxfem), an electromagnetic simulation software based on the finite element method.

The system is modeled by a 2DEG of density  $2.5 \times 10^{11}$  cm<sup>-2</sup>, separated by a 100 nm-thick AlGaAs layer from the surface, on top of which 300 nm-wide and 100 nm-thick metallic gates are defined. The local density is computed in the Thomas-Fermi approximation and represented as a colormap in Fig.S6a-c for different gate voltages. The surface occupied by each electrons is then represented by a circle whose diameter is equal to  $\sqrt{1/n_{2D}}$ .

To estimate how many electrons are likely to localize in the QPC channel, we compare these results with the expected criterion for Wigner crystallization. As the density of an electronic system is reduced, the Wigner-Seitz radius  $r_s$ , defined as the ratio of half the inter-particle distance to the Bohr radius  $a_B$ , enlarges ( $a_B = 10$  nm in GaAs). When  $r_s$  overcomes the critical value  $r_{sc}$ , the electronic system undergoes a phase transition from a Fermi liquid to a Wigner crystal<sup>[12]</sup>. In two dimensions, numerical estimates of  $r_{sc}^{2D}$  indicate a value close to 37[13], which is never reached in our simulations. The Fermi liquid description therefore holds for the 2D regions. In one dimension however, the value of  $r_{sc}^{1D}$  depends on the confinement potential strength but is closer to unity [14]. In Ref.[8],  $r_{sc}^{1D}$ <br>has been estimated to ~ 0.7, and this criterion was shown to be reached below the first co a few crystallized electrons in the channel. In Figs. S6d to S6f, we show estimates of the 1D density  $n_{1D}$  in the one-dimensional region, and indicate the region where the electron transport is effectively 1D, i.e. where only one transverse electronic mode is permitted. In this 1D region, the 1D density is below the critical density  $1/(2r_{sc}^{1D}a_B)$ where we can expect Wigner crystallization (below the red line). In the following, we calaculate how many electrons the crystallization region may contain. This estimation shows that no crystallization is expected for a completely closed QPC (Fig.S6a,d), since both 1D regions on the two sides of the QPC barrier contain less than one electron

charge. As the QPC opens, the density in the two 1D regions on both sides of the barrier increase, up to a point where each of these regions may contain one electron charge (Fig.S6b,e). For larger opening, the crystallization regions merge across the full QPC length and becomes large enough to contain 3 electrons (Fig.S6c,f).

Though a more accurate calculation including quantum effects would be required to estimate the exact behavior of localized electrons[15, 16], our simple approach indicates that one electron may be localized in each 1D region olongbibliographyf the channel near QPC pinch-off (Fig.S6b), but this situation is not favored anymore as the QPC closes (Fig.S6a). Therefore the energy level corresponding to this spontaneously localized state may evolve in a very peculiar way with the QPC opening, and could correspond to the behavior of the phase shift observed in our TSGM experiment.

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